

## AMENDMENTS

Please amend the above-identified application as follows:

### In the Claims

In accordance with 37 C.F.R. § 1.121, please substitute the following clean copy text for the pending claims of the same number:

1 15. (Newly Added) An organic light emitting device, comprising:  
2 an electrode;  
3 a current self-limiting structure; and  
4 an organic stack located between said electrode and said current  
5 self-limiting structure, said current self-limiting structure located non-adjacent said  
6 organic stack.

1 16. (Newly Added) The device as defined in claim 15, wherein said current  
2 self-limiting structure resides in contact with said electrode.

1 17. (Newly Added) The device as defined in claim 15, wherein said current  
2 self-limiting structure is applied as a patterned lattice structure over said electrode.

1 18. (Newly Added) The device as defined in claim 15, wherein said current  
2 self-limiting structure is applied as a grid defining windows in which said electrode is  
3 applied.

1 5 19. (Newly Added) The device as defined in claim 15, wherein said current  
2 self-limiting structure comprises an anisotropically conductive material.

1 6 20. (Newly Added) The device as defined in claim 15, further including a  
2 photoresist material in contact with said current self-limiting structure and said  
3 electrode.

1 7 21. (Newly Added) The device as defined in claim 15, wherein said current  
2 self-limiting structure resides between said electrode and a conducting layer.

1 8 22. (Newly Added) The device as defined in claim 21, wherein said  
2 conducting layer is embedded within said current self-limiting structure.

1 9 23. (Newly Added) The device as defined in claim 21, wherein said  
2 conducting layer resides over said current self-limiting structure.

1 10 24. (Newly Added) A method for increasing the reliability of an organic  
2 light emitting device, comprising the steps of:  
3 forming an organic light emitting device; and  
4 incorporating a current self-limiting structure within said organic light  
5 emitting device and non-adjacent said organic stack.

1 11 25. (Newly Added) The method as defined in claim 24, wherein said current  
2 self-limiting structure is formed in contact with an electrode of said organic light  
3 emitting device.

1 12 26. (Newly Added) The method as defined in claim 24, wherein said current  
2 self-limiting structure is formed as a patterned lattice in contact with an electrode of  
3 said organic light emitting device.

1 13 27. (Newly Added) The method as defined in claim 24, wherein said current  
2 self-limiting structure is applied as a grid defining windows in which an electrode of  
3 said organic light emitting device is applied.

1 14 28. (Newly Added) The method as defined in claim 24, wherein said current  
2 self-limiting structure comprises an anisotropically conductive material.